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ENS210

Relative Humidity and Temperature Sensor with I²C Interface

General Description

The ENS210 integrates one relative humidity sensor and one high-accuracy temperature sensor. The device is encapsulated in a QFN4 package and includes an I²C slave interface for communication with a master processor.

Ordering Information and Content Guide appear at end of datasheet.

Key Benefits and Features

The benefits and features of ENS210, Relative Humidity and Temperature Sensor with I²C Interface are listed below:

Figure 1: Added Value of Using ENS210

Benefits	Features
Ultra-accurate	 Temperature sensor (±0.2°C) Relative humidity sensor (±3.5%RH)
Wide sensing range	 Temperature operating range (-40°C to 100°C) Relative humidity operating range (0% to 100%)
Wide operating voltage	• 1.71V to 3.60V
Small foot-print	• 2.0mm x 2.0mm x 0.75mm
Industry standard two-wire interface	Standard (100kbit/s) and fast (400kbit/s) I ² C
Low power	 Automatic low-power standby when not measuring Active current: 7.1µA @ 1Hz (1.8V) Standby current: 40nA
Cost effective	 Digital pre-calibrated relative humidity and temperature sensor Output directly in %RH and Kelvin Wide supply voltage range
High reliability	Long-term stability



Applications

The ENS210 applications include:

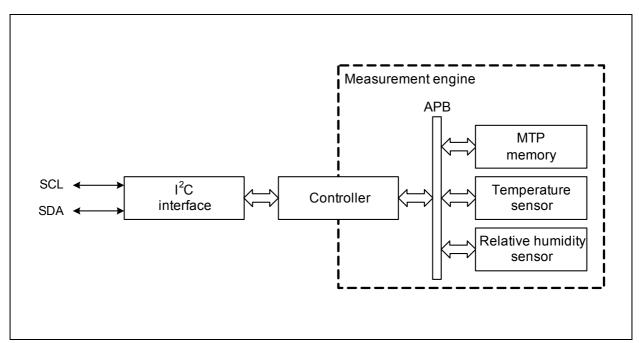
- Mobile phones, tablets and wearables
- · Home and building climate control systems
- Transportation condition monitoring
- Wireless sensor nodes
- · Personal health and wellness monitoring
- Laser printers
- Home appliance
- Industrial automation (e.g. server rooms)
- Baby incubators
- · Weather stations

Block Diagram

The internal block diagram of ENS210 is shown in Figure 2. The I²C (communication) interface is connected to a controller which acts as the command interpreter and as bus master of the internal Advanced Peripheral Bus (APB). The memory and sensors are slaves of the APB. The MTP memory is used to store the sensor calibration parameters and unique ID.

To reduce power consumption the controller only powers the measurement engine when needed.

Figure 2: Functional Blocks of ENS210



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Pin Assignments

The ENS210 pin assignment is described in Figure 3 and Figure 4.

Figure 3: Pin Diagram of ENS210

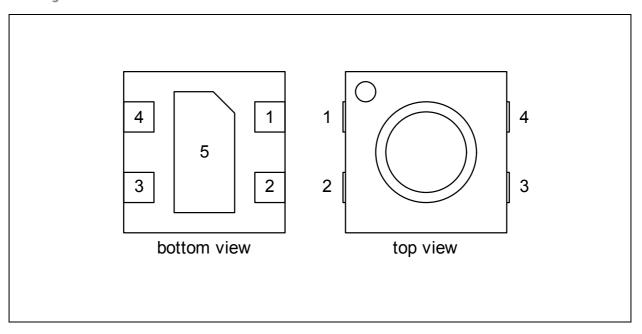


Figure 4: Pin Description of ENS210

Pin Number	Pin Name	Description	
1	V_{DD}	Supply voltage	
2	SCL	I ² C bus serial clock input (SCL)	
3	SDA	I ² C bus serial bidirectional data line (SDA)	
4	V _{SS}	Ground supply voltage; must be connected	
5	V _{SS}	Ground supply voltage; must be connected	



Absolute Maximum Ratings

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated under Electrical Characteristics is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Figure 5: Absolute Maximum Ratings of ENS210

Symbol	Parameter	Min	Max	Units	Comments
		Electrical	Parameters		
V _{DD}	Supply voltage	-0.30	4.60	V	
I _{lu}	Latch-up current		100	mA	I/O; -0.5V _{DD} < V _I < 1.5V _{DD} ; T _j < 125°C
		Electrostat	ic Discharge		
ESD _{HBM}	Human body model; all pins	±2000		V	JEDEC JS-001-2014
ESD _{CDM}	Charged model device; all pins	±5	±500		JEDEC JS-002-2014
	Oper	ating and S	torage Cond	itions	
MSL	Moisture sensitivity level		1		Maximum floor life time is unlimited
T _{STRG}	Storage temperature	10	50	°C	
RH _{NC}	Relative humidity (non-condensing)	20 60		%RH	Preferably in sealed ESD bag
T _A	Operating ambient temperature	-40 100		°C	
H _A	Operating ambient relative humidity	0	100	%RH	

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Electrical Characteristics

All limits are guaranteed. The parameters with min and max values are guaranteed with production tests or SQC (Statistical Quality Control) methods.

Figure 6: Electrical Characteristics

Symbol	Parameter	Conditions	Min	Typ ⁽¹⁾	Max	Unit
V _{DD}	Supply voltage	Max ripple 100mV _{PP} between 0-1MHz	1.71	1.80 (3.30)	3.60	V
		Standby state		0.04 (0.3)		μΑ
I _{DD}	Supply current	Continuous run mode		58 (56)		μΑ
		T and RH measurement at 1Hz		7.1 (6.9)		μΑ
V _{IH}	High-level input voltage		0.7×V _{DD}		V _{DD} +0.5	V
V _{IL}	Low-level input voltage		-0.5		0.3×V _{DD}	V
I _{OL}	Low-level output	V _{OL} = 0.4V	3			mA
'OL	current	V _{OL} = 0.6V	6			mA

Note(s):

- 1. Values in parenthesis are for $\rm V_{\rm DD}{=}3.30~\rm V.$
- 2. T_{A} = 25 $^{\circ}\text{C}$ and at 1.80 V supply voltage, unless otherwise specified

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I²C Timing Characteristics

ENS210 is compliant to the I²C standard; it supports standard and fast mode as per I²C-bus specifications [UM10204, I²C-bus specification and user manual, Rev. 6, 4 April 2014].

Temperature Sensor Characteristics

Figure 7: Temperature Sensor Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{range}	Temperature range		-40		100	°C
T _{acc}	Tomporaturo accuracy (3)	$T_A = 0$ °C to 70°C; 3 σ			0.2	°C
'acc	T _{acc} Temperature accuracy ⁽³⁾	$T_A = -40^{\circ}\text{C to } 100^{\circ}\text{C}; 3\sigma$			0.5	°C
T _{res}	Temperature resolution			0.016		°C
t _{resp}	Response time (2)	T step of 10°C by submersion (in 0°C to 70°C range); τ 63 % ⁽¹⁾		1		S
T _{rep}	Temperature repeatability	3σ of consecutive measurement values at constant conditions	-0.1		0.1	°C
ΔΤ	Temperature long term drift			0.005		°C / year

Note(s):

- 1. 63% indicates that if a T step of 10°C, e.g. from 20°C to 30°C is made, it will take t_{resp} seconds to reach 63% of that step.
- 2. In an application the temperature response time depends on heat conductivity of the sensor PCB.
- 3. Accuracy specifications are defined before soldering of the product in an application. Refer to ENS210 application note. Maximum accuracy specification refers to 3 standard deviations assuming normal distribution of accuracy errors. After industrial calibration of sensors, each sensor is tested on typical room conditions (e.g. 25°C 45%RH) and only sensors passing the verification qualify for customer deliveries.

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Relative Humidity Sensor Characteristics

Figure 8: Relative Humidity Sensor Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
H _{range}	Relative humidity range		0		100	%RH
H _{acc}	Relative humidity	$T_A = 25$ °C; RH = 20%RH to 80%RH; excluding hysteresis; 3σ			3.5	%RH
··acc	accuracy ⁽³⁾	$T_A = 25$ °C; RH = 0%RH to 100%RH; excluding hysteresis; 3 σ			5	%RH
H _{res}	Relative humidity resolution			0.03		%RH
t _{resp}	Response time ⁽⁴⁾	RH step of 20%RH (in 40%RH to 80%RH range); τ 63% ⁽¹⁾ ; 1m/s flow; $T_A = 25$ °C		3	5	S
H _{hys}	Relative humidity hysteresis	$T_A = 25$ °C; RH = 20%RH to 90%RH; 30minutes exposure time		±1		%RH
H _{rep}	Relative humidity repeatability	3σ of consecutive measurement values at $T_A = 25^{\circ}\text{C}$ and RH = 40%RH		±0.1		%RH
ΔΗ	Relative humidity long term drift ⁽²⁾	T _A = 25°C		0.25		%RH / year

Note(s):

- $1.\,63\%\ indicates\ that\ if\ an\ RH\ step\ of\ 20\%RH\ is\ made,\ e.g.\ from\ 40\%RH\ to\ 60\%RH,\ it\ will\ take\ t_{resp}\ seconds\ to\ reach\ 63\%\ of\ that\ step.$
- 2. Values are linearized averages over the lifetime of the product. Due to non-linear behavior a larger drift is expected in the first years.
- 3. Maximum accuracy specification refers to 3 standard deviations assuming normal distribution of accuracy errors. After industrial calibration of sensors, each sensor is tested on typical room conditions (e.g. 25°C and 45%RH) and only sensors passing the verification qualify for customer deliveries.
- 4. Device only performance. Application response time will depend on the design-in of the sensor

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System Timing Characteristics

Figure 9: System Timing Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{booting}	Booting time ⁽¹⁾			1	1.2	ms
t _{conv}	Conversion time (2)	T only		105	110	ms
conv	Conversion time **	T and RH		122	130	ms

Note(s):

- 1. Time in transient state *booting* (see Figure 10).
- 2. Includes t_{booting}

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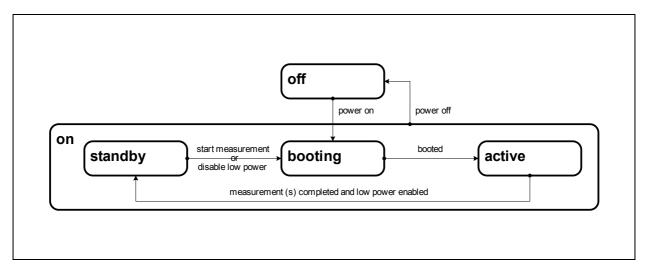


Functional Description

The ENS210 integrates two sensor blocks: temperature and relative humidity.

The device is normally in the *standby* state (Figure 10): the measurement engine (see Figure 2) is unpowered, but the I²C interface is operational and register write/read operation can be performed. When a measurement command is given, the device is first *booting* to *active* then it starts a measurement. When the measurement is completed, the device returns to the *standby* state. Since the I²C interface is operational in *standby*, the measurement result can be read out.

Figure 10: The ENS210 Power States



In continuous run mode (see Register SENS_RUN) or when low power is disabled (see Register SYS_CTRL), the device remains in *active* state.

The system power status is observable (see Register SENS_STAT).

When powering up from off, the device is first booting to active, but then falls immediately back to standby (since no measurement is pending, and by default low power is enabled).

Note that the *booting* state is a transient state (the system automatically transitions to the next state – *active*); the booting time is given in Figure 9.

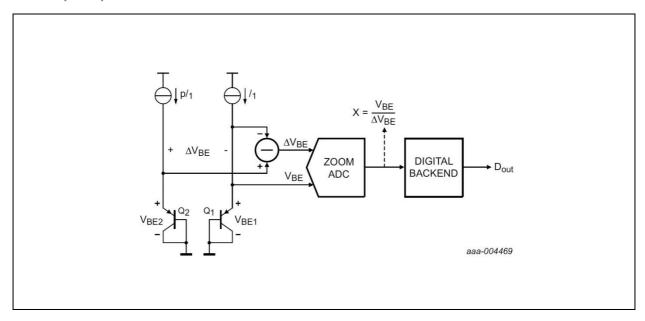
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Temperature Sensor

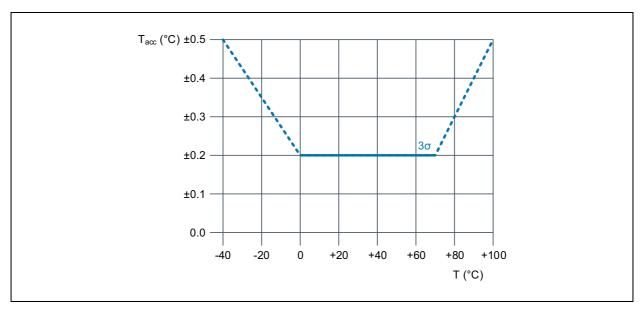
The temperature sensor block (Figure 11) determines the ambient temperature, and outputs a calibrated value in Kelvin.

Figure 11:
Band Gap Temperature Measurement



The temperature is measured using a high-precision (12 bits) zoom-ADC. The analog part is able to measure a strongly temperature dependent $X = V_{BE}/\Delta V_{BE}$. The X is found by first applying a coarse search (successive approximation), and then a sigma-delta in a limited range. The accuracy of the sensor is shown in Figure 12. The conversion time is shown in Figure 9.

Figure 12:
Absolute Accuracy of the Temperature Sensor



Note(s):

1. Dash line indicates natural physical behavior

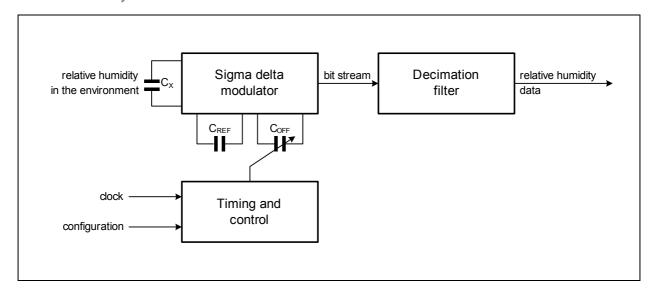
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Relative Humidity Sensor

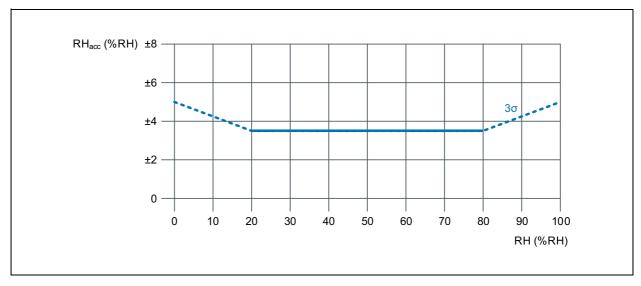
The relative humidity sensor as shown in Figure 13 determines the ambient relative humidity and outputs a calibrated value in %RH. The transducer (the C_X on the top left) consists of a large-area capacitor covered with a humidity-sensitive material. The capacitance change is proportional to the change in relative humidity, and has a linear dependence on temperature. The capacitance is measured by a high-precision $2^{\rm nd}$ order sigma-delta converter.

Figure 13: Relative Humidity Sensor



Reading the relative humidity sensor will output a temperature compensated value. The accuracy of the sensor is shown in Figure 14. The conversion time is shown in Figure 9.

Figure 14:
Absolute Accuracy of the Relative Humidity Sensor at 25°C



Note(s):

1. Dash line indicates natural physical behavior

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The I²C Interface

The ENS210 is an I²C slave device. The I²C interface supports standard (100kbit/s) and fast (400kbit/s) mode.

Details on I^2C protocol is according to I^2C -bus specifications [UM10204, I^2C -bus specification and user manual, Rev. 6, 4 April 2014].

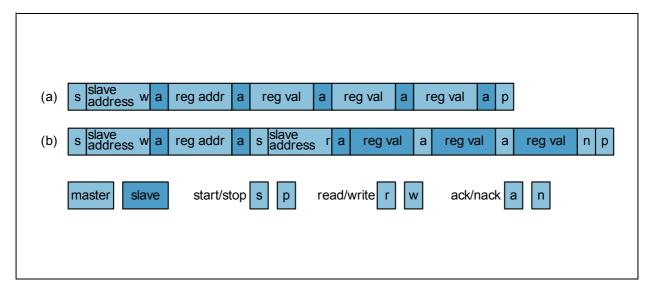
The device applies all mandatory I²C protocol features for slaves: START, STOP, Acknowledge, 7-bit slave address, and also the optional clock stretching. The latter means that the master must support clock stretching in order to successfully communicate with the ENS210.

None of the other optional features (10-bit slave address, General Call, Software reset, or Device ID) are supported, nor are the master features (Synchronization, Arbitration, START byte).

I²C Operations on Registers

The ENS210 uses a register model to interact with it. This means that an I²C master can write a value to one of the registers of a slave, or that it can read from one of the registers of the slave. In the ENS210, registers are addressed using 1 byte. The values stored in a register are also 1 byte. However, the ENS210 implements "auto increment" which means that it is possible to read, for example, two bytes by supplying the address of the first byte and then reading two bytes.

Figure 15: I²C Transaction Formats



A typical write transaction (see Figure 15 a) therefore has the following format. The master initiates a transaction with a so-called start condition "s". This blocks the bus. Next, the master sends the 7 bits ENS210 slave address followed by a 1 bit direction (a 0 indicating write "w"). This byte is acknowledged "a" by the slave. The master continues by sending the 8 bit register address, which is acknowledged by the slave. This

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register address is stored in an internal CRA register ("Current Register Address"). Finally, the master sends the 8 bit register value, which is acknowledged by the slave (or nack'ed when the address is not writeable). This value is written to the register pointed to by the CRA, and the CRA is incremented by 1. Optionally, the master sends more 8 bit values, for the next registers (auto incrementing CRA), each of which is (n)ack'ed by the slave. Finally, the master generates a stop condition "p", unblocking the bus for other transactions.

A read transaction (see Figure 15 b) starts with a write (of the register address), followed by a read. Consequently, it has the following format. The master initiates the transaction with a start condition. Next, the master sends the 7 bits ENS210 slave address followed by a 1 bit direction (a 0 indicating write). This byte is acknowledged by the slave. The master continues by sending the 8 bit register address, which is acknowledged by the slave and stored in the CRA register. Then the master sends another start condition (a so-called repeated start condition, keeping the bus blocked) followed by the 7 bits ENS210 slave address followed by a 1 bit direction (a 1 indicating read "r"), which is acknowledged by the slave. Next, the slave sends an 8 bits register value from the register pointed to by the CRA register, and the CRA is incremented by 1. This byte is acknowledged by the master. The master may read another 8 bits (auto increment feature) from the slave and acknowledge that, until the master sends a nack "n" followed by a stop to unblock the bus.

The ENS210 has an 8 bit address space, potentially addressing 256 registers. In reality, only few addresses are actually backed by a register (see Register Overview). All other addresses are reserved. A write transaction to a reserved (or read-only) register causes a not-acknowledge. A read transaction for a reserved register will return a 0.

The I²C Slave Address

The ENS210 is an I²C slave device with a fixed slave address of 0x43. This means that the first byte after a start condition is 1000 011x, where x indicates the data direction, so 0x86 (1000 0110) for write and 0x87 (1000 0111) for read.

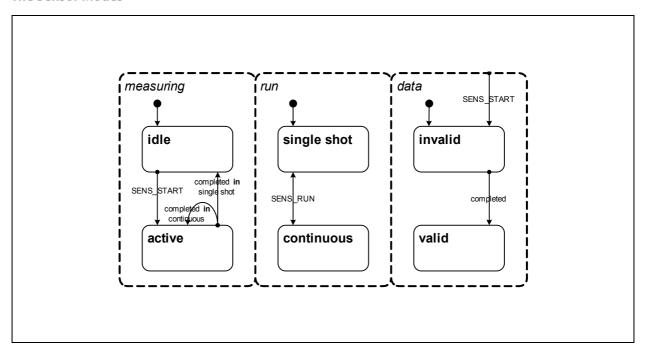
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Sensor Control

The ENS210 contains a temperature and a relative humidity sensor. Both sensors have two run modes: single shot run mode and continuous run mode (enabled via SENS_RUN), see Figure 16.

Figure 16: The Sensor Modes



When in the *single shot* run mode, starting a measurement is under control of the master. By default a sensor is idle; it can be started by writing a 1 to the corresponding bit in SENS_START. After a start, the sensor stops when the measurement is completed. Whether a sensor is idle or active measuring can be detected by reading SENS_STAT. The measured values can be obtained via their respective readout registers (T_VAL and H_VAL). Writing to SENS_STOP in single shot has no effect.

When in the *continuous* run mode, the sensor performs measurement after measurement after a 1 is written to the corresponding bit in SENS_START. The result of each measurement is stored in the aforementioned readout registers. Writing 1 to the corresponding bit in SENS_STOP stops the repeat cycle after the ongoing measurement is completed.

The device operates in a step-wise way. In each step, either one or both sensors are active. The step ends when the measurement(s) are completed. For the next step, the device inspects its register settings, and either one or both sensors are activated again, or there is no measurement request and the device goes into standby (unless low power is disabled by SYS_CTRL).

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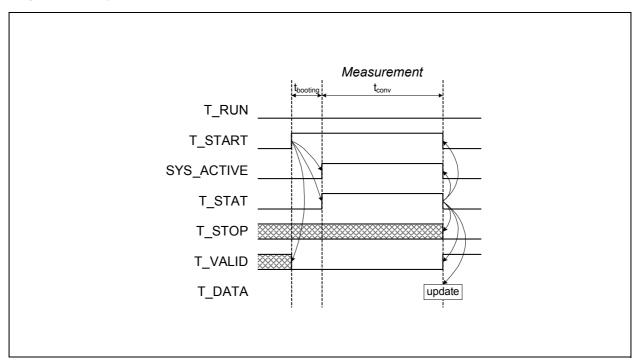


This means that multiple writes to START during a step have no effect; the measurement is started once, and only a write to START after the measurement has completed starts the measurement again. Similarly, multiple writes to STOP have no effect; when the measurement completes (in continuous mode) the stop request is effectuated once. When START and STOP are both requested, the measurement is started, and when completed, stopped.

Sensor Timing

There are differences between single shot measurements and continuous measurements. Figure 17 shows the timing of a single shot T measurement.

Figure 17:
Single Shot Temperature Measurement



Signal T_RUN is written low to select a single shot measurement. Note that T_STOP is typically low (cleared by a previous measurement), but its state is ignored in a single shot measurement. T_START is written high to start measuring: T_VALID in T_VAL is cleared and the device starts *booting* to *active*. Once active SYS_ACTIVE goes high, and measurement starts (T_STAT goes high).

When the measurement is completed (T_STAT goes low) the data register (T_DATA) becomes valid (T_VALID goes high) and the device goes back to *standby* (SYS_ACTIVE goes low). The T_START and T_STOP are cleared.

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Figure 18: Continuous Temperature Measurement

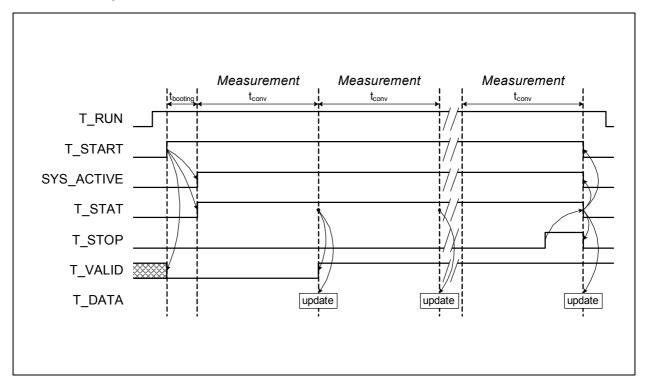


Figure 18 shows the timing of a continuous T measurement.

Signal T_RUN is written high to select a continuous measurement. Note that T_STOP is typically low (cleared by a previous measurement), and it should stay low otherwise continuous mode will stop after one measurement. T_START is written high to start measuring: T_VALID in T_VAL is cleared and the device starts booting to active. Once active SYS_ACTIVE goes high, and measurement starts (T_STAT goes high).

When the first measurement is completed the data register (T_DATA) becomes valid (T_VALID goes high), and the device starts a new measurement. When the next measurement is completed the data register (T_DATA) is updated; T_VALID stays high. The device starts a new measurement.

At some point in time, a stop command is given (T_STOP is written high). As soon as the current measurement is completed, the data register (T_DATA) is once more updated and the device goes back to *standby* (SYS_ACTIVE goes low). The T_START and T_STOP are cleared.

Note that writes to the SENS_XXX registers only take effect when no measurement is ongoing. In other words, measurements are always sequential (so we can have three types: T only, RH only or T and RH and changes occur when the measurements are finished.

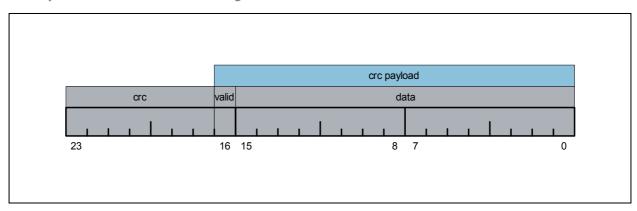
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The Sensor Readout Registers

The sensor readout registers (T_VAL and H_VAL) consist of three parts: the actual measured data, a valid flag and a checksum (see Figure 19). It is not mandatory to read the valid flag or the checksum when reading the data.

Figure 19:
The Layout of the Sensor Readout Registers



The *checksum* is a cyclic redundancy check over the data and the valid flag; the stored checksum is the result of CRC-7 (polynomial x7+x3+1, see https://en.wikipedia.org/wiki/Cyclic_redundancy_check) with 0x7F as initial vector (i.e. with all bits flipped), see Computing CRC-7 for sample C code.

The valid flag is cleared when a measurement is started (irrespective of the run mode). Once the measurement is completed the valid flag is set. In continuous mode, a new measurement is then started without clearing the valid flag; so data is always valid after the first measurement (but it might be several milliseconds old).

The data field is a 16 bits fixed point number, whose format and unit depends on the sensor (see Register T_VAL and Register H_VAL).

To ensure consistent view, these multi-byte readout registers are double buffered. When the first byte (i.e. the byte with the lowest register address) is read, the device copies all bytes from the measurement registers to the I²C registers, and then the value from the first I²C register is returned. Reads to the other bytes of the multi-byte register (i.e. with higher register addresses) are always directly from the I²C registers.

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Computing CRC-7

CRC algorithm uses a 7 bit polynomial (see lines 4, 5, and 6), and a 17 bit payload. The crc7() function below uses the following constants defining the CRC width, (the coefficients of the) polynomial and the initial vector (start value of the CRC), and some constants describing the payload data size.

```
7654 3210
// Polynomial
                0b 1000 1001 ~ x^7+x^3+x^0
                      8
                0x
                           9
#define CRC7WIDTH 7
                           // 7 bits CRC has polynomial of 7th order (has 8 terms)
                     0x89 // The 8 coefficients of the polynomial
#define CRC7POLY
#define CRC7IVEC
                     0x7F // Initial vector has all 7 bits high
// Payload data
#define DATA7WIDTH 17
#define DATA7MASK ((1UL<<DATA7WIDTH)-1) // 0b 0 1111 1111 1111 1111
#define DATA7MSB (1UL<<(DATA7WIDTH-1)) // 0b 1 0000 0000 0000 0000
```

The crc7 (val) function returns the CRC-7 of a 17 bits value val.

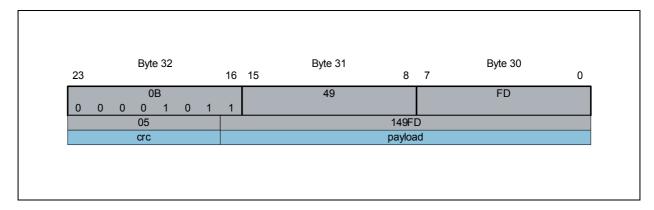
```
// Compute the CRC-7 of 'val' (should only have 17 bits)
uint32_t crc7( uint32_t val ) {
    // Setup polynomial
    uint32_t pol= CRC7POLY;
    // Align polynomial with data
    pol = pol << (DATA7WIDTH-CRC7WIDTH-1);
    // Loop variable (indicates which bit to test, start with highest)
    uint32_t bit = DATA7MSB;
    // Make room for CRC value
    val = val << CRC7WIDTH;
    bit = bit << CRC7WIDTH;
    pol = pol << CRC7WIDTH;
    // Insert initial vector
    val |= CRC7IVEC;
    // Apply division until all bits done
    while(bit & (DATA7MASK<<CRC7WIDTH)) {
         if( bit & val ) val ^= pol;
         bit >>= 1;
         pol >>= 1;
    }
     return val;
}
```

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Suppose that T VAL (address 30, 31 and 32) reads FD 49 0B, corresponding (little endian) with the number 0B49FD, see Figure 20. This leads to a CRC of 05 over a payload of 149FD. See the next paragraph for details on processing this data.

Figure 20: **T_VAL** Readout



Processing T_VAL and H_VAL

This paragraph shows a possible implementation of reading T and RH.

The following fragment starts a combined single shot measurement, waits and reads the measurement results. It assumes the availability of i2c reg write and i2c reg read primitives as well as a sleep routine (rtk tsk sleep). The format specifiers in the printf's are kept simple (%d instead of %ld or even PRId32 from inttypes.h); they need adaptation on e.g. 16 bits platforms.

```
// Record I<sup>2</sup>C transaction status
bool i2c_ok= true;
// Start T and H (write 03 to register 22 in device 86)
uint8_t wbuf[]= { 0x03 };
i2c_ok &= i2c_reg_write(0x86, 0x22, wbuf, sizeof wbuf);
// Wait for measurements to complete
rtk_tsk_sleep(150);
// Read T and H (read 6 bytes starting from 0x30 in device 86)
uint8 t rbuf[6];
i2c_ok &= i2c_reg_read(0x86, 0x30, rbuf, sizeof rbuf);
// Extract T_VAL and H_VAL (little endian), assumes 32 bits wordsize
uint32_t t_val= (rbuf[2]<<16) + (rbuf[1]<<8) + (rbuf[0]<<0);
uint32_t h_val= (rbuf[5]<<16) + (rbuf[4]<<8) + (rbuf[3]<<0);
```

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The following fragment processes the T measurement as available in t_val. It relies on the crc7() function as shown previously.

```
// Extract (and print) the fields
uint32_t t_data = (t_val>>0) & 0xffff;
uint32_t t_valid= (t_val>>16) & 0x1;
uint32_t t_crc = (t_val>>17) & 0x7f;
printf( did, "ENS210: T: %06x %02x %01x %04x\n", t_val, t_crc, t_valid, t_data );
// Check the CRC
uint32_t t_payl = (t_val>>0) & 0x1ffff;
bool t_crc_ok= crc7(t_payl)==t_crc;
// Convert to float (and print)
float TinK = (float)t_data / 64; // Temperature in Kelvin
float TinC = TinK - 273.15; // Temperature in Celsius
float TinF = TinC * 1.8 + 32.0; // Temperature in Fahrenheit
printf( did, "ENS210: T: (i2c=%d crc=%d valid=%d) %5.1fK %4.1fC %4.1fF\n", i2c_ok, t_crc_ok, t_valid, TinK, TinC, TinF );
```

The following fragment processes the RH measurement as available in h val. It is similar to the t val processing.

```
// Extract (and print) the fields
uint32_t h_data = (h_val>>0) & 0xffff;
uint32_t h_valid= (h_val>>16) & 0x1;
uint32_t h_crc = (h_val>>17) & 0x7f;
printf( did, "ENS210: H: %06x %02x %01x %04x\n", h_val, h_crc, h_valid, h_data );
// Check the CRC
uint32_t h_payl = (h_val>>0) & 0x1ffff;
bool h_crc_ok= crc7(h_payl)==h_crc;
// Convert to float (and print)
float H = (float)h_data/512; // relative humidity (in %)
printf( did, "ENS210: H: (i2c=%d crc=%d valid=%d) %2.0f%%\n", i2c_ok, h_crc_ok, h_valid, H );
```

If registers 30 to 35 would contain fd 49 0b 6c 2e f5 (i.e. T_VAL in blue and H VAL in green) the code would print

```
ENS210: T: 0b49fd 05 1 49fd
ENS210: T: (i2c=1 crc=1 valid=1) 296.0K 22.8C 73.0F
ENS210: H: f52e6c 7a 1 2e6c
ENS210: H: (i2c=1 crc=1 valid=1) 23%
```

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Reading PART_ID and UID

The first 2 registers (PART_ID and UID) are only available in *active* state. There are two ways to read them:

- Dedicated read action
 - Disable low power (set LOW_POWER to 0)
 - Wait for t_{booting} to get into active state (check SYS_ACTIVE to be 1)
 - Read the ID register(s)
 - Re-enable low power (set LOW_POWER to 1)
- Piggybacking on a measurement
 - Start a measurement (write 0b01, 0b10, or 011 to SENS_START)
 - Wait for t_{booting} to get into active state (check SYS_ACTIVE to be 1)
 - Read the ID register(s)
 - Ensure the device is still in *active* state (check SYS_ACTIVE to be 1)

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Register Description

This section describes the I²C registers of the ENS210.

Register Overview

Note that some registers are actually spread over multiple addresses. For example, T_VAL at address 30 is spread over 3 addresses (its "Size" is 3). This could be rephrased as follows: there are three registers T_VAL0, T_VAL1, and T_VAL2 at addresses 30, 31, and 32 respectively.

Figure 21: Register Overview

Address	Name	Size	Access	Description
0x00	PART_ID	2	Read (active only)	Identifies the part as ENS210
0x02	<unused></unused>	2	Read	
0x04	UID	8	Read (active only)	Unique identifier
0x0C	<reserved></reserved>	4		
0x10	SYS_CTRL	1	Read/Write	System configuration
0x11	SYS_STAT	1	Read	System status
0x12	<reserved></reserved>	14		
0x21	SENS_RUN	1	Read/Write	The run mode (single shot or continuous)
0x22	SENS_START	1	Write	Start measurement
0x23	SENS_STOP	1	Write	Stop continuous measurement
0x24	SENS_STAT	1	Read	Sensor status (idle or measuring)
0x25	<reserved></reserved>	11		
0x30	T_VAL	3	Read	Temperature readout
0x33	H_VAL	3	Read	Relative humidity readout
0x36	<reserved></reserved>	202		

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Detailed Register Description

Register PART_ID (Address 0x00)

This 2 byte register identifies the part number in little endian (ENS210). This register is only available in *active* state; see Reading PART_ID and UID for instructions of reading it.

Figure 22: Register PART_ID

Address 0x00		PART_ID			
Bits	Field Name	Default	Access	Field Description	
15:0	PART_ID	0x0210	Read	Identifies this device as an ENS210	

Register UID (Address 0x04)

This 8 byte register uniquely identifies a single device among all ENS210 devices. This register is only available in *active* state; see Reading PART_ID and UID for instructions of reading it.

Figure 23: Register UID

Address 0x04		UID		
Bits	Field Name	Default	fault Access Field Description	
63:0	UID	Varies	Read	Unique device id

Register SYS_CTRL (Address 0x10)

This 1 byte register controls the system.

Figure 24: Register SYS_CTRL

А	ddress 0x10	SYS_CTRL		
Bits	Field Name	Default	Access	Field Description
7	RESET	0	Write	Write 1 to reset the device
6:1	<reserved></reserved>	0b000000	Read/Write	Keep to 0's
0	LOW_POWER	0b1	Read/Write	Controls the automatic low power. 0: Disabled (device stays in <i>active</i>) 1: Enabled (device goes to <i>standby</i> when measurement complete)

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Register SYS_STAT (Address 0x11)

This 1 byte register indicates the system status.

Figure 25: Register SYS_STAT

Address 0x11				SYS_STAT
Bits	Field Name	Default	Access	Field Description
7:1	<reserved></reserved>	0b0000000	Read	Reads 0's
0	SYS_ACTIVE	0b1	Read	The system power state 0: System is in <i>standby</i> or <i>booting</i> state 1: System is in <i>active</i> state

Register SENS_RUN (Address 0x21)

This 1 byte register configures the run modes (single shot or continuous) of the sensors.

Figure 26:
Register SENS_RUN

Address 0x21		SENS_RUN			
Bits	Field Name	Default	Access	Field Description	
7:2	<reserved></reserved>	0b000000	Read/Write	Keep to 0's	
1	H_RUN	0b0	Read/Write	The run mode of the relative humidity sensor 0: Relative humidity sensor operates in single shot mode 1: Relative humidity sensor operates in continuous mode	
0	T_RUN	0b0	Read/Write	The run mode of the temperature sensor 0: Temperature sensor operates in single shot mode 1: Temperature sensor operates in continuous mode	

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Register SENS_START (Address 0x22)

This 1 byte register starts a measurement for the sensors.

Figure 27:
Register SENS_START

Address 0x22		SENS_START			
Bits	Field Name	Default	Access	Field Description	
7:2	<reserved></reserved>	0b000000	Read/Write	Keep to 0's	
1	H_START	0b0	Read/Write	Write a 1 to start a relative humidity sensor measurement Writing 0 has no effect (helps in multiple access)	
0	T_START	0b0	Read/Write	Write a 1 to start a temperature sensor measurement Writing 0 has no effect (helps in multiple access)	

Register SENS_STOP (Address 0x23)

This 1 byte register stops a continuous measurement for the sensors.

Figure 28:
Register SENS_STOP

Address 0x23		SENS_STOP			
Bits	Field Name	Default	Access	Field Description	
7:2	<reserved></reserved>	0b000000	Write	Write 0's	
1	H_STOP	0b0	Write	Write a 1 to stop a continuous relative humidity sensor measurement Writing 0 has no effect (helps in multiple access)	
0	T_STOP	0b0	Write	Write a 1 to stop a continuous temperature sensor measurement Writing 0 has no effect (helps in multiple access)	

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